-100mA / -50V Digital transistors (with built-in resistors)

DTA115EM / DTA115EE / DTA115EUA / DTA115EKA

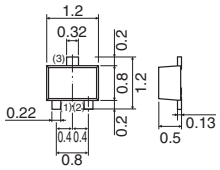
● Applications
Inverter, Interface, Driver

● Features
1)Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2)The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
3)Only the on/off conditions need to be set for operation, making the device design easy.
4)Higher mounting densities can be achieved.

● Structure
PNP epitaxial planar silicon transistor (Resistor built-in type)

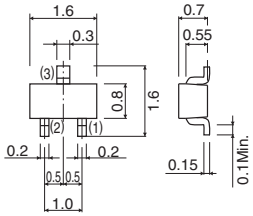
● Dimensions (Unit : mm)

DTA115EM



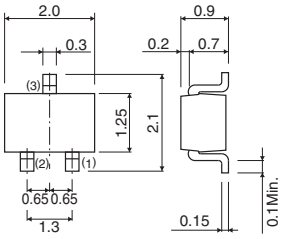
ROHM : VMT3
(1) IN
(2) GND
(3) OUT
Abbreviated symbol : 19

DTA115EE



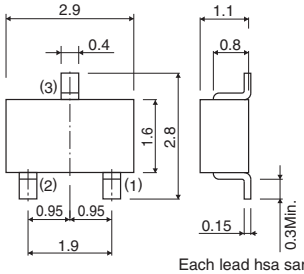
ROHM : EMT3
(1) GND
(2) IN
(3) OUT
Abbreviated symbol : 19

DTA115EUA



ROHM : UMT3
EIAJ : SC-70
(1) GND
(2) IN
(3) OUT
Each lead hsa same dimensions
Abbreviated symbol : 19

DTA115EKA

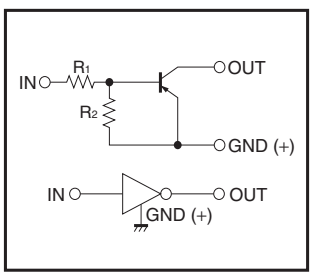


ROHM : SMT3
EIAJ : SC-59
(1) GND
(2) IN
(3) OUT
Each lead hsa same dimensions
Abbreviated symbol : 19

● Packaging specifications

	Package	VMT3	EMT3	UMT3	SMT3
	Packging type	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146
Part No.	Basic ordering unit (pieces)	8000	3000	3000	3000
DTA115EM		○	–	–	–
DTA115EE		–	○	–	–
DTA115EUA		–	–	○	–
DTA115EKA		–	–	–	○

● Inner circuit



R_1=R_2=100kΩ

● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Supply voltage		V_{CC}	−50	V
Input voltage		V_I	−40 to +10	V
Output current		I_O	−20	mA
		$I_{C(Max.)}$	−100	
Power dissipation	DTA115EM / DTA115EE	P_D	150	mW
	DTA115EUA / DTA115EKA		200	
Junction temperature		Tj	150	°C
Storage temperature		Tstg	−55 to +150	°C

● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	−	−	−0.5	V	V_{CC}= −5V, I_O= −100μA
	$V_{I(on)}$	−3	−	−		V_O= −0.3V, I_O= −1mA
Output voltage	$V_{O(on)}$	−	−0.1	−0.3	V	I_O= −5mA, I_I= −0.25mA
Input current	I_I	−	−	−0.15	mA	V_I= −5V
Output current	$I_{O(off)}$	−	−	−0.5	μA	V_{CC}= −50V, V_I=0V
DC current gain	G_I	82	−	−	−	I_O= −5mA, V_O= −5V
Input resistance	R_1	70	100	130	kΩ	−
Resistance ratio	R_2/R_1	0.8	1	1.2	−	−
Transition frequency	f_T *	−	250	−	MHz	V_{CE}= −10V, I_E=5mA, f=100MHz

* Characteristics of built-in transistor

● Electrical characteristic curves

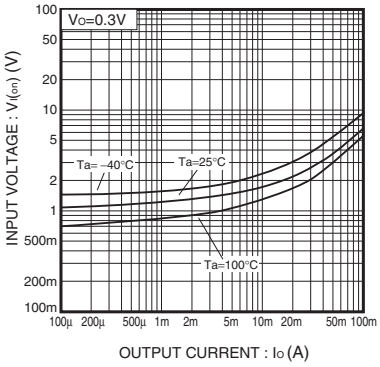


Fig.1 Input voltage vs. Output current (ON characteristics)

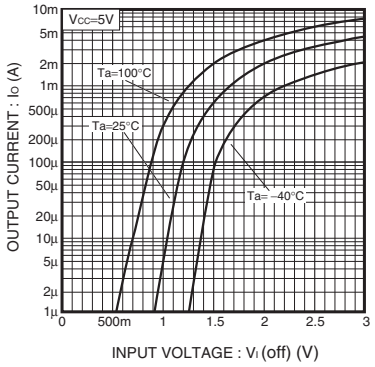


Fig.2 Output current vs. Input voltage (OFF characteristics)

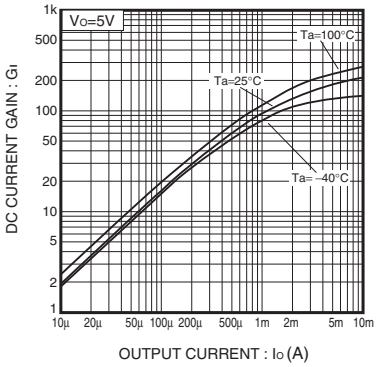


Fig.3 DC current gain vs. Output current

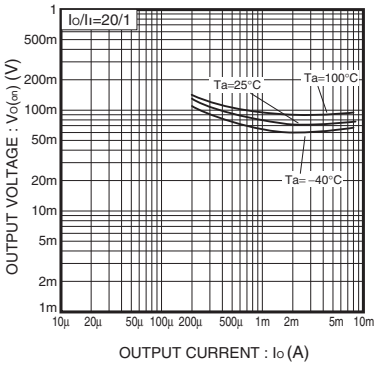


Fig.4 Output voltage vs. Output current

Notes

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